

Density-Matrix based Extended Lagrangian Born-Oppenheimer Molecular Dynamics

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Extended Lagrangian Born-Oppenheimer molecular dynamics [Phys. Rev. Lett. **100**, 123004 (2008)] is presented for Hartree-Fock theory, where the extended electronic degrees of freedom are represented by a density matrix that accounts for fractional occupation numbers at elevated electronic temperatures. A 4th-order metric tensor, $\mathcal{T} \equiv \mathcal{K}^T \mathcal{K}$, is used in the generalized extended harmonic oscillator of the Lagrangian that generates the dynamics of the electronic degrees of freedom. The kernel, $\mathcal{K}$, is given in terms of an inverse Jacobian of a matrix residual function and appears in the equation of motion for the extended harmonic oscillator. A tunable low-rank approximation of this 4th-order kernel is used for the integration of the electronic degrees of freedom. In contrast to regular direct Born-Oppenheimer molecular dynamics simulations, no iterative self-consistent field optimization is required prior to the force evaluations. The formulation and algorithms provide a general guide to implement extended Lagrangian Born-Oppenheimer molecular dynamics for quantum chemistry, density functional theory, and semiempirical methods using a density matrix formalism.

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I. INTRODUCTION

Extended Lagrangian Born-Oppenheimer molecular dynamics (XL-BOMD) [1–14] is a general theoretical framework that provides a practical approach to efficient quantum-based molecular dynamics simulations. XL-BOMD is based on an extended Lagrangian formulation of first principles molecular dynamics in the spirit of Car-Parrinello molecular dynamics [5, 15–19], where the electronic degrees of freedom are included as extended classical dynamical field variables that are propagated along the molecular coordinates. In this way the costly overhead of the iterative, self-consistent field (SCF) optimization of the electronic ground state, which is required in regular Born-Oppenheimer molecular dynamics simulation, can be avoided or reduced. Various versions and techniques of XL-BOMD have been used and implemented in a number of software packages, including applications for density functional theory, semi-empirical electronic structure theory, polarizable force fields, excited state dynamics, and superfluidity [3, 4, 7, 8, 10, 14, 20–32].

Originally, XL-BOMD [1, 6, 33, 34] was referred to as “Time-reversible Born-Oppenheimer Molecular Dynamics”, which often had to be combined with a few self-consistent-field optimization iterations in each time step to provide stable molecular trajectories. Recent generalized formulations of XL-BOMD avoid the non-linearities in the electronic energy formulation and the need for any iterative self-consistent-field optimization [9, 13]. It is only these most recent SCF-free formulations of XL-BOMD [9, 13, 35] that are considered in this article.

The more recent formulations of XL-BOMD include a metric tensor, $\mathcal{T} \equiv \mathcal{K}^T \mathcal{K}$, in the extended harmonic oscillator. The tensor is formed by the square of a kernel, $\mathcal{K}$, that appears in the Euler-Lagrange’s equations of motion for the electronic degrees of freedom. The kernel is given by the inverse of the Jacobian of a residual function, which can be expensive to calculate explicitly in each time step. Initially the kernel was approximated by a fixed, scaled delta function, $\mathcal{K} \approx -c\delta(\mathbf{r} - \mathbf{r}')$, with $c \in [0, 1]$. This approximation works well for non-reactive chemical systems. However, for reactive chemical systems, including charge instabilities, the scaled delta-function approximation is often not sufficiently accurate. The scaled delta-function approximation can be adjusted and improved by a single rank-1 update [13]. Unfortunately, this fixed rank-1 adjustment is sometimes also not adequate. Instead, a tunable rank- m approximation based on a Krylov subspace approximation was recently proposed [35]. This adjustable approximation significantly extends the range of systems that can be studied with XL-BOMD simulations. So far, this tunable rank- m kernel approximation has been applied only to formulations of XL-BOMD where the extended electronic degrees of freedom is described by a vector or a scalar field, for example, the atomic Mulliken net charges in semi-empirical electronic structure theory or the charge density. In these cases the kernel, $\mathcal{K}$, and the metric tensor, $\mathcal{T}$, represent second-order tensor mappings between vectors or scalar fields. This is not suitable for many first principles electronic structure methods. In this article, I will instead present a kernel formalism for XL-BOMD using Hartree-Fock theory with a density matrix as the extended electronic degrees of freedom. Density matrices are used frequently in quantum chemistry methods as well as in other electronic structure techniques and is therefore often a natural choice for the extended electronic degrees of freedom in implementations of XL-BOMD. In this case we have to use a 4th-order metric tensor representation of $\mathcal{T}$ in the harmonic extension of XL-BOMD, where the corresponding kernel, $\mathcal{K}$, represents a 4th-order tensor mapping between matrices. The density-matrix adapted methodology requires modifications and it has some limitations compared to the previous formulations. The main goal of this article, apart from introducing a

higher-order metric tensor formalism, is to provide a general guide how to implement XL-BOMD in electronic software packages using an effective single-particle density matrix formalism. A computational prototype scheme written in pseudocode, Alg. 3, summarizes the theory and the algorithms. The discussion is mainly focused on Hartree-Fock theory, but the theory is general and should be directly applicable also to density functional theory or semi-empirical methods using a density matrix formalism.

I will first briefly review regular direct Born-Oppenheimer molecular dynamics using a Hartree-Fock approximation that has been generalized to finite electronic temperatures using fractional occupation numbers. Thereafter I present the ideas behind XL-BOMD, its Lagrangian formulation and the equations of motion. The integration of the equations of motion is then discussed, in particular, how the 4th-order kernel is approximated in the integration of the electronic equation of motion. I then present a more complete computational scheme for XL-BOMD in the density matrix based Hartree-Fock formalism. At the end I demonstrate some examples before the final discussion and the summary. A more general description, background and analysis of XL-BOMD can be found in Refs. [9, 13, 35].

II. XL-BOMD FOR HARTREE-FOCK THEORY WITH FRACTIONAL OCCUPATION NUMBERS

A. Direct Born-Oppenheimer molecular dynamics

In direct Born-Oppenheimer molecular dynamics based on the spin-restricted Hartree-Fock approximation [36, 37] that has been generalized to account for fractional occupation numbers and the electronic free energy at finite electronic temperatures [38], the potential energy surface, $U(\mathbf{R})$, can be defined through a constrained minimization of a non-linear density-matrix expression of the free energy, where

$$U(\mathbf{R}) = \min_D \{2\text{Tr}[hD] + \text{Tr}[DG(D)] - 2T_e\mathcal{S}(\{f\})\} + V_{nn}(\mathbf{R}) \quad (1)$$

under the constraints that

$$\begin{aligned} D &= \sum_i f_i C_i C_i^T, \\ C_i^T S C_j &= \delta_{i,j}, \\ \sum_i f_i &= N_{\text{occ}}. \end{aligned} \quad (2)$$

In this thermal Hartree-Fock formulation $\mathbf{R} = \{R_I\}$ are the nuclear coordinates; $D \in \mathbb{R}^{N \times N}$ is the constrained single-particle density matrix; $S \in \mathbb{R}^{N \times N}$ is the basis-set overlap matrix; $h \in \mathbb{R}^{N \times N}$ is the single-electron Hamiltonian matrix; N_{occ} the number of occupied states (each doubly occupied); $\{f_i\} \in [0, 1]$ are the fractional occupation numbers; $\{C_i\}$ is some set of vectors; V_{nn} is the ion-ion repulsive term; $G(D) \in \mathbb{R}^{N \times N}$ is the electron-electron interaction matrix corresponding to the Coulomb, $J(D) \in \mathbb{R}^{N \times N}$, and exchange matrix, $K(D) \in \mathbb{R}^{N \times N}$, i.e.

$$G(D) = 2J(D) - K(D); \quad (3)$$

T_e is the electronic temperature; and $\mathcal{S}(\{f\})$ is the electronic entropy contribution,

$$\mathcal{S}(\{f\}) = -k_B \sum_i (f_i \ln(f_i) + (1 - f_i) \ln(1 - f_i)), \quad (4)$$

where k_B is Boltzmann's constant. At $T_e = 0$ the entropy contribution vanishes and the occupation numbers, f_i , are either 1 or 0 as in regular Hartree-Fock theory. In principle, it is only this ground state solution at $T_e = 0$ that corresponds to a Born-Oppenheimer potential energy surface. However, since the finite temperature solution in the thermal Hartree-Fock theory is a straightforward generalization I will still call the free energy potential at $T_e > 0$ a Born-Oppenheimer potential energy surface. The matrices, h , $G(D)$, and S in Eq. (1) have matrix elements that have been calculated using some atomic-orbital basis set, $\{\phi_i(\mathbf{r})\}_{i=1}^N$, for example, where the overlap matrix, S , has matrix elements $S_{i,j} = \langle \phi_i | \phi_j \rangle$, $i, j = 1, 2, \dots, N$. The ground state density matrix, $D_{\min}$, which is attained at the constrained minimum in Eq. (1) and defines the Born-Oppenheimer potential energy surface, $U(\mathbf{R})$, can be calculated as a solution of the generalized non-linear algebraic eigenvalue equation,

$$F(D)C_i = SC_i\epsilon_i, \quad (5)$$

where $F(D)$ is the Hartree-Fock Hamiltonian or Fockian,

$$F(D) = h + G(D). \quad (6)$$

The density matrix, D , is then given as a weighted outer product of the eigenstate vectors, $\{C_i\}_{i=1}^N$, where

$$D = \sum_i f_i C_i C_i^T, \quad (7)$$

with the Fermi occupation factors (i.e. the fractional occupation numbers) given by

$$f_i = \left(e^{\beta(\epsilon_i - \mu_0)} + 1 \right)^{-1}, \quad (8)$$

where the chemical potential, μ_0 , is chosen such that

$$\sum_i f_i = N_{\text{occ}}, \quad (9)$$

and $\beta = 1/(k_B T_e)$ is the inverse temperature. The solution of $D_{\min}$ in the constrained, non-linear, variational formulation in Eq. (1), given through Eqs. (5) - (9), can be found through an iterative self-consistent-field optimization procedure, where a new approximate density matrix is updated and mixed with previous approximate solutions until the matrix commutation between $F(D)$ and D vanishes at convergence, i.e. when $D = D_{\min}$. This iterative optimization is often computationally expensive and yet, in practice, never exact.

Once the ground state optimization has been performed, the interatomic forces can be calculated [39–41] using the Hellmann-Feynman theorem, i.e. using the property that $\partial U(\mathbf{R})/\partial D = 0$, which is valid for the exact, fully SCF optimized, ground state, $D_{\min}$. The equations of motion,

$$M_I \ddot{R}_I = -\frac{\partial U(\mathbf{R})}{\partial R_I}, \quad (10)$$

where M_I are the atomic masses, can then be integrated. This can be done, for example, by using the time-reversible and symplectic leapfrog velocity Verlet scheme that then generates the molecular trajectories time step by time step.

The constant of motion is given by the Born-Oppenheimer Hamiltonian,

$$\mathcal{H}_{\text{BO}} = \frac{1}{2} \sum_I M_I \dot{R}_I^2 + U(\mathbf{R}). \quad (11)$$

B. Some ideas behind XL-BOMD in a density matrix formalism

By extrapolating the ground state density matrix from previous time steps it is possible to significantly reduce the computational overhead of the iterative ground state optimization required in Eq. (1). However, since the variational ground state optimization is approximate and never complete (i.e. $\partial U(\mathbf{R})/\partial D \approx 0$), the forces evaluated using the Hellmann-Feynman theorem are never exactly conservative. This leads to a systematic drift in the total energy, because of a broken time-reversal symmetry in the fictitious propagation of the underlying electronic degrees of freedom that is generated through the extrapolation [16, 42, 43]. The alternative, to restart the ground state optimization in each new time step from overlapping atomic densities, preserves the time-reversal symmetry and avoids a systematic drift in the total energy, but the computational cost is significantly higher. Extended Lagrangian Born-Oppenheimer molecular dynamics (XL-BOMD) [1–11, 13, 14] is a framework developed to avoid these shortcomings.

The main idea behind XL-BOMD is based on a backward error analysis. Instead of calculating approximate forces through and expensive iterative ground-state optimization procedure for an underlying “exact” Born-Oppenheimer potential energy surface, we can calculate exact forces in a fast and simple SCF-free way, but for an underlying approximate *shadow* potential energy surface. In this way we can reduce the computational cost and at the same time restore a consistency between the calculated forces and the underlying shadow potential.

Density-matrix based XL-BOMD is given in terms of an extended Lagrangian formulation of the dynamics using four approximations: 1) The non-linear density matrix energy expression that is minimized in Eq. (1) is linearized around some approximate density matrix, P , which is assumed to be close to the exact ground state, D_{min} . The constrained variational optimization of this linearized energy expression provides the P -dependent shadow potential energy surface, which can be determined in a single SCF-free step without the approximate iterative ground state optimization; 2) The approximate density matrix, P , around which the linearization is performed, is included as an extended dynamical variable for a fictitious electronic degrees of freedom that evolves through a harmonic oscillator that is centered around the best available approximation to the exact ground state density matrix, D_{min} . In this way P will remain close to the optimized ground state density; 3) The harmonic potential corresponding to the best available approximation of the ground state density matrix is given by the square-norm of the residual matrix function, $D[P] - P$, formed by the difference between P and the optimized solution of the linearized energy expression, $D[P]$, using a generalized metric tensor, $\mathcal{T} \equiv \mathcal{K}^T \mathcal{K}$, where $\mathcal{K}$ is the inverse Jacobian of the residual matrix function; 4) The Euler-Lagrange equations of motion are then derived in an adiabatic limit, where the frequency of the harmonic oscillator extension is assumed to be high compared to the highest frequency of the nuclear degrees of freedom and the fictitious electron mass parameter goes to zero. This classical adiabatic limit corresponds to a Born-Oppenheimer-like

approximation for the extended electronic degrees of freedom and leads to a pair of coupled equations of motion for the nuclear and the electronic degrees of freedom.

It is only the most recent formulations of XL-BOMD that include the generalized metric tensor in the harmonic oscillator extension [9, 13, 35]. The tensor acts such that the dynamical density matrix variable, P , for the fictitious electronic degrees of freedom, oscillate around a much closer approximation to the exact Born-Oppenheimer ground state compared to the variationally optimized solution of the linearized energy functional, $D[P]$. The metric tensor and its various low-rank approximations in the integration of the electronic degrees of freedom have so far not been discussed explicitly for a density matrix formulation. It has only been presented in formulations where the extended electronic degrees of freedom have been the electron density or the net Mulliken charges, which only requires a metric tensor of second order. The main purpose of this article is to present XL-BOMD using a density matrix formalism, which requires a 4th-order metric tensor, $\mathcal{T}$, that performs a mapping between matrices. I will also use a general atomic-orbital representation of the extended electronic degrees of freedom, i.e. as in Ref. [7], with a dynamical matrix variable $X = PS$ instead of the density matrix P or its orthogonalized form, $P^\perp$. Although a transformation between the different representations can be performed easily, they are not equivalent in the integration.

The density matrix formulation presented for the thermal Hartree-Fock approximation is quite general and should be straightforward to apply to a broad class of quantum chemistry techniques, including density functional theory and semi-empirical methods. For density functional theory, the only necessary modification is to replace the Coulomb and exchange matrices, $G(P) = 2J(P) - K(P)$, with the corresponding Coulomb matrix, V_C , and exchange-correlation matrix, V_{xc} .

C. Extended Lagrangian

The theory of XL-BOMD is based on an extended Lagrangian formulation and the four approximations presented in Sec. II B. The extended Lagrangian for spin-restricted thermal Hartree-Fock theory, which includes fractional occupation numbers at finite electronic temperatures, is defined by

$$\mathcal{L}(\mathbf{R}, \dot{\mathbf{R}}, X, \dot{X}) = \frac{1}{2} \sum_I M_I \dot{R}_I^2 - \mathcal{U}(\mathbf{R}, X) + \frac{1}{2} \text{Tr} [\dot{X}^2] - \frac{1}{2} \mu \omega^2 \text{Tr} [(D[X]S - X)^T \mathcal{T} (D[X]S - X)]. \quad (12)$$

Here $\mathbf{R}$ and $\dot{\mathbf{R}}$ are the atomic positions and their velocities; $X \in \mathbb{R}^{N \times N}$ and $\dot{X} \in \mathbb{R}^{N \times N}$ are the dynamical matrix variables (where X corresponds to PS as discussed in the previous section, Sec. II B) that represent the extended electronic degrees of freedom; $\mathcal{U}(\mathbf{R}, X)$ is the shadow potential for the electronic free energy at some electronic temperature T_e that approximates the corresponding exact Born-Oppenheimer free energy surface; $\mathcal{T} \equiv \mathcal{K}^T \mathcal{K}$ is the metric tensor; μ is a fictitious electronic mass parameter; and ω is the frequency of the harmonic oscillator extension. $D[X] \in \mathbb{R}^{N \times N}$ is the X -dependent density matrix given by the constrained variational minimization of a linearized density matrix function for the electronic energy,

$$D[X] = \arg \min_D \{ 2\text{Tr} [hD] + \text{Tr} [(2D - XS^{-1}) G (XS^{-1})] - 2T_e \mathcal{S}(\{f\}) \}. \quad (13)$$

The same density matrix constraints as in Eq. (2) are used and the minimization is performed for the lowest variationally stationary solution. It is assumed that $P = XS^{-1} \approx D[X]$ is an approximate ground state density matrix and $G(P)$ corresponds to the regular Coulomb and exchange matrices, i.e. $G(P) = 2J(P) - K(P)$. The dynamical matrix variable X , in the harmonic extension of the Lagrangian in Eq. (12), oscillates around an approximate electronic ground state solution represented by $D[X]S$. The shadow potential energy surface, $\mathcal{U}(\mathbf{R}, X)$, in Eq. (12) is given by

$$\mathcal{U}(\mathbf{R}, X) = 2\text{Tr}[hD[X]] + \text{Tr}[(2D[X] - XS^{-1})G(XS^{-1})] - T_e\mathcal{S}(\{f\}) + V_{nn}(\mathbf{R}), \quad (14)$$

which is a close approximation to the fully relaxed ground state Born-Oppenheimer potential energy surface if the size of the residual matrix function, $D[X]S - X$, is small.

The expression for the harmonic oscillator of the extended Lagrangian in Eq. (12) includes a metric tensor,

$$\mathcal{T} \equiv \mathcal{K}^T \mathcal{K}, \quad (15)$$

where $\mathcal{K} \in \mathbb{R}^{N^2 \times N^2}$ is a kernel that acts as a 4th-order tensor, which performs mappings between matrices. This kernel, $\mathcal{K}$, is defined from the inverse of the Jacobian, $\mathcal{J}$, of the residual matrix function, where

$$\mathcal{J}_{ij,kl} = \frac{\partial(\{D[X]S\}_{ij} - X_{ij})}{\partial X_{kl}}, \quad (16)$$

and

$$\mathcal{K} = \mathcal{J}^{-1}. \quad (17)$$

We will never deal with any full 4th-order tensor or its inverse explicitly, only how its low-rank approximations act on a matrix. Low-rank approximations are necessary to avoid a large computational overhead even for fairly small molecular systems.

D. Variational optimization of the density matrix

The main computational cost of XL-BOMD is associated with the constrained variational optimization of the density matrix $D[X]$ in Eq. (13). However, the cost is drastically reduced compared to the non-linear minimization required in direct Born-Oppenheimer molecular dynamics in Eq. (1). If the approximate Fockian in a non-orthogonal atomic-orbital representation is given by

$$F \equiv F(X) = h + G(XS^{-1}), \quad (18)$$

with the orthogonalized matrix representation,

$$F_0^\perp = Z^T F Z, \quad (19)$$

then the constrained density matrix minimization in Eq. (13) can be performed by first calculating

$$D^\perp[X] = \left(e^{\beta(F_0^\perp - \mu_0 I)} + I \right)^{-1}, \quad (20)$$

where μ_0 is the chemical potential set such that $\text{Tr}[D^\perp[X]] = N_{\text{occ}}$, followed by the transform back to the non-orthogonal atomic orbital representation, where

$$D[X] = ZD^\perp[X]Z^T. \quad (21)$$

Here $Z \in \mathbb{R}^{N \times N}$ is the inverse overlap factorization matrix, which is determined by the relation

$$Z^T S Z = I, \quad (22)$$

where $I \in \mathbb{R}^{N \times N}$ is the identity matrix. This density-matrix calculation in Eq. (20) can be performed using a straightforward matrix diagonalization or by using a serial Chebyshev or recursive Fermi-operator expansion scheme [41, 44–49]. The diagonalization has a computational complexity that scales cubically, $\mathcal{O}(N^3)$, with the number of basis functions, whereas the Fermi-operator expansion methods can be made to scale only as $\mathcal{O}(N^3)$ if we can take advantage of thresholded sparse matrix algebra [50, 51]. Linear scaling, $\mathcal{O}(N)$, methods can also be used to calculate Z [12].

The constrained optimization of $D[X]$ in Eq. (13) is given without any iterative self-consistent field optimization, since the matrix functional in Eq. (13) is linear in D . The non-linear self-consistent field problem in regular Born-Oppenheimer molecular dynamics, which requires an iterative solution, has been removed. The computational cost of XL-BOMD is therefore significantly reduced compared to direct Born-Oppenheimer molecular dynamics. However, $D[X]$ is not the exact Born-Oppenheimer ground state solution. Nevertheless, it is a variationally stationary solution of the shadow potential energy surface, $\mathcal{U}(\mathbf{R}, X)$, in Eq. (14), in the same way as the exact D_{min} is the variationally stationary solution for the regular Born-Oppenheimer potential energy surface, $U(\mathbf{R})$, in Eq. (1). This simplifies the calculation of interatomic forces that are consistent with the shadow potential energy surface and we can avoid contributions from terms including $\partial D[X]/\partial R_I$, since

$$\frac{\partial \mathcal{U}(\mathbf{R}, X)}{\partial D[X]} \frac{\partial D[X]}{\partial R_I} = 0. \quad (23)$$

With XL-BOMD we are thus able to calculate accurate conservative forces that are consistent with the shadow potential. This is achieved without requiring any costly iterative self-consistent field optimization procedure prior to the force evaluations. Moreover, as long as $P = XS^{-1}$ is a reasonably close approximation to the exact self-consistent ground state density, i.e. as long as the residual matrix function $D[X]S - X$ is small, the shadow potential energy surface, $\mathcal{U}(\mathbf{R}, X)$, in Eq. (14), is close to the exact Born-Oppenheimer potential, $U(\mathbf{R})$, [13].

E. Equations of motion

Atoms are moving on a slow time scale compared to the electronic motion. If the electrons are in the ground state initially we may therefore assume they will evolve adiabatically along the electronic ground state as the atoms are moving. This is the reasoning behind the Born-Oppenheimer approximation in quantum-based molecular dynamics simulations [19, 52, 53]. In the derivation of the equations of motion from the Euler-Lagrange equations for the extended Lagrangian in Eq. (12) we can also apply an adiabatic approximation that separates the motion between

the nuclear and the extended electronic degrees of freedom. In this classical adiabatic approximation, we assume that ω that determines the frequency of the extended electronic degrees of freedom, $X(t)$ and $\dot{X}(t)$, is large compared to some highest frequency, Ω , of the nuclear degrees of freedom, $\mathbf{R}(t)$ and $\dot{\mathbf{R}}(t)$. In the derivation of the Euler-Lagrange equations of motion of the Lagrangian in Eq. (12) we then let $\omega/\Omega \rightarrow \infty$, such that $\mu\omega = \text{constant}$. In this classical adiabatic “Born-Oppenheimer-like” limit [9, 13], for which $\mu \rightarrow 0$, it can be shown that the size of the residual $D[X] - X$ scales as $1/\omega^2$ and that $\partial\mathcal{U}(\mathbf{R}, X)/\partial X$ scales linearly with the residual $D[X] - X$. The equations of motion for XL-BOMD in this adiabatic “mass-zero” limit are then given by

$$M_I \ddot{R}_I = \left. \frac{\partial \mathcal{U}(\mathbf{R}, X)}{\partial R_I} \right|_X, \quad (24)$$

for the nuclear degrees of freedom and

$$\ddot{X} = -\omega^2 \mathcal{K} (D[X]S - X), \quad (25)$$

for the electronic degrees of freedom. The corresponding constant of motion is given by the shadow Hamiltonian,

$$\begin{aligned} \mathcal{H}_{\text{XL-BOMD}} &= \frac{1}{2} \sum_I M_I \dot{R}_I^2 + \mathcal{U}(\mathbf{R}, X) \\ &= \frac{1}{2} \sum_I M_I \dot{R}_I^2 + 2\text{Tr} [\hbar D[X]] + \text{Tr} [(2D[X] - XS^{-1}) G (XS^{-1})] - T_e \mathcal{S}(\{f\}) + V_{nn}(\mathbf{R}). \end{aligned} \quad (26)$$

Equations (24) and (25) together with the constant of motion in Eq. (26) are the three central equations that governs the dynamics of XL-BOMD for thermal Hartree-Fock theory.

III. INTEGRATING XL-BOMD

Integrating the equations of motion, Eqs. (24) and (25), includes some technical challenges. One problem is to keep the extended electronic degrees of freedom synchronized with the nuclear degrees of freedom. In a perfectly time-reversible integration, numerical noise will accumulate, which eventually leads to a divergence between the exact Born-Oppenheimer ground state that is determined by the nuclear coordinates and the electronic degrees of freedom around which the density matrix energy function is linearized. $P = XS^{-1}$ is then no longer a close approximation to the ground state, $D_{\min}$, and the accuracy of the linearized functional in Eq. (13) breaks down. Another problem is to approximate the inverse Jacobian kernel, $\mathcal{K}$, in the electronic equations of motion. The full exact kernel defined in Eqs. (16) and (17) is expensive to calculate and its action on the residual $D[X]S - X$ has to be approximated in the integration of the electronic degrees of freedom, Eq. (25).

A. Modified Verlet scheme with damping

For the integration of the combined nuclear and electronic degrees of freedom in Eqs. (24) and (25) we can use a modified leapfrog velocity Verlet scheme [2, 3, 34] that includes an additional dissipative term in the integration of

the extended electronic degrees of freedom. This additional term breaks the time-reversal symmetry to some chosen higher odd-order in the integration time step, δt , which dampens the accumulation of numerical noise that otherwise could cause instabilities in a perfectly reversible integration. In this way the evolution of the electronic degrees of freedom stays synchronized to the dynamics of the nuclear motion. The modified leapfrog velocity Verlet integration scheme for the integration of the nuclear and electronic degrees of freedom is given by

$$\begin{aligned}
\dot{R}_I(t + \frac{\delta t}{2}) &= \dot{R}_I(t) + \frac{\delta t}{2} \ddot{R}_I(t), \\
R_I(t + \delta t) &= R_I(t) + \delta t \dot{R}_I(t + \frac{\delta t}{2}), \\
X(t + \delta t) &= 2X(t) - X(t - \delta t) + \delta t^2 \ddot{X}(t) + \alpha \sum_{k=0}^{k_{\max}} c_k X(t - k\delta t), \\
\dot{R}_I(t + \delta t) &= \dot{R}_I(t + \frac{\delta t}{2}) + \frac{\delta t}{2} \ddot{R}_I(t + \delta t).
\end{aligned} \tag{27}$$

The last term in the integration of $X(t)$ is the additional damping term, where the coefficients, α and $\{c_k\}_{k=0}^{k_{\max}}$, as well as a dimensionless constant, $\kappa = \delta t^2 \omega^2$, have been optimized for various values of $k_{\max}$ and are given in Refs. [34]. In the initial time step $X(t_0 - k\delta t)$ for $k = 0, 1, \dots, k_{\max}$ are all set to the fully converged regular Born-Oppenheimer ground state density, $D_{\min}$, times the overlap matrix S , i.e. at t_0 we set $X(t_0 - k\delta t) = D_{\min} S$ for $k = 0, 1, \dots, k_{\max}$. A reasonably well-converged iterative self-consistent field optimization is thus required, but only in the first initial time step. The modified Verlet integration scheme works similar to a Langevin dynamics, but where the stochastic term is generated by the intrinsic numerical noise of the system instead of an external random number generator and where the dissipation is given by a higher-order time-derivative term instead of a first-order velocity-driven friction term. In general, this solution works well without any significant drift in the constant of motion on time scales relevant for quantum-based Born-Oppenheimer molecular dynamics. However, a number of alternative integration schemes for XL-BOMD have been proposed and analyzed [11, 24, 29, 31, 54, 55].

B. Krylov subspace approximation of the inverse Jacobian kernel

The integration of the electronic degrees of freedom in Eq. (27) requires the calculation of the second-order time derivative of $X(t)$, which is given by the electronic equations of motion in Eq. (25). This equation includes the inverse Jacobian kernel, $\mathcal{K} \in \mathbb{R}^{N^2 \times N^2}$, that is given from the Jacobian of the residual matrix function $(D[X]S - X) : \mathbb{R}^{N \times N} \rightarrow \mathbb{R}^{N \times N}$ using Eqs. (16) and (17). A technique to perform a tunable and adaptive approximation of the kernel for the integration of the electronic degrees of freedom in XL-BOMD was recently developed [35], but for a residual function $f(n) = (q[n] - n) : \mathbb{R}^N \rightarrow \mathbb{R}^N$. That method was derived from an expression of the Jacobian of $f(n)$, which is based on a set of general directional derivatives,

$$f_{v_i} = \left. \frac{\partial f(n + \lambda v_i)}{\partial \lambda} \right|_{\lambda=0}, \tag{28}$$

along directions $v_i \in \mathbb{R}^N$ instead of partial derivatives, $\partial f(n)/\partial n_i$, with respect to the individual components of n . The Jacobian, $J \in \mathbb{R}^{N \times N}$, in this case, can then be approximated by a rank- m expression,

$$J \approx \sum_{i,j=1}^m f_{v_i} L_{ij} v_j^T, \quad (29)$$

where $L = O^{-1}$, which is the inverse overlap with matrix elements, $O_{ij} = v_i^T v_j$. The directional derivatives are calculated with quantum perturbation theory and the directions $\{v_i\}$ are chosen from a Krylov subspace approximation [35]. The kernel is then determined by a psedoinverse of the low-rank Jacobian. In combination with preconditioning, this provides a rapidly converging low-rank approximation of the kernel in the integration of the electronic degrees of freedom. The method is directly related to a single step in so-called Jacobian-free Newton Krylov methods used in the iterative solution of systems of non-linear equations [56] and the corresponding residual minimization methods [57–59].

Here we need to adapt the previos approximation method of the Jacobian and its pseudoiverse [35] to the residual matrix function, $(D[X]S - X) : \mathbb{R}^{N \times N} \rightarrow \mathbb{R}^{N \times N}$. We start by rewriting Eq. (25) in a more general but equivalent form, using a preconditioner, $\mathcal{K}_0$, i.e. where

$$\ddot{X} = -\omega^2 (\mathcal{K}_0 \mathcal{J})^{-1} \mathcal{K}_0 (D[X]S - X). \quad (30)$$

In the ideal case we assume that $\mathcal{K}_0 \mathcal{J} \approx \mathcal{I}$, where $\mathcal{I}$ is the 4th-order identity tensor. We will then try to find a low-rank approximation of how the preconditioned kernel, $(\mathcal{K}_0 \mathcal{J})^{-1}$, acts on the modified residual, $\mathcal{K}_0 (D[X]S - X)$. For the 2nd-order kernels it is possible to construct efficient preconditioners by a direct full calculation of the kernel at the initial time step, which then can be kept as a constant preconditioner during the molecular dynamics simulation. This preconditioning technique generates rapidly converging low-rank approximations of the kernel. With the 4th-order kernel this direct method is no longer possible, except for very small molecular systems. I will therefore not pursue the use of preconditioners in this article, even if they can be constructed in different forms [60]. I will still keep $\mathcal{K}_0$ in the formalism, but only to keep it general. As will be demonstrated in the examples, we can achieve accurate low-rank approximations even without preconditioner, i.e. when the identity is used as a preconditioner and $\mathcal{K}_0 = \mathcal{I}$. Another difference to the original Krylov subspace approximation is that the metric of the inner product has to be modified. Instead of a vector-product, $\langle v_i, v_j \rangle = v_i^T v_j$, where $v_i \in \mathbb{R}^N$, we will use the matrix generalization, $\langle V_i, V_j \rangle = \text{Tr}[V_i^T V_j]$, where $V_i \in \mathbb{R}^{N \times N}$. The matrix norm, $\|V_i\| = \sqrt{\langle V_i, V_i \rangle} = \sqrt{\text{Tr}[V_i^T V_i]}$, then corresponds to the Frobenius norm. The general principle for the original formulation can then be kept. With this matrix generalization of the method in Ref. [35], the rank- m Krylov subspace approximation for how the preconditioned kernel acts on the modified matrix residual function is given by

$$(\mathcal{K}_0 \mathcal{J})^{-1} \mathcal{K}_0 (D[X]S - X) \approx \sum_{i,j=1}^m V_i M_{ij} \langle W_j, W_0 \rangle. \quad (31)$$

The algorithm that generates the matrices $V_i \in \mathbb{R}^{N \times N}$, $M \in \mathbb{R}^{m \times m}$, and $W_i \in \mathbb{R}^{N \times N}$, is given in Alg. 1. It is an adaptive scheme, where the order m of the rank- m approximation is tunable by a chosen tolerance level. With this

tunable rank- m Krylov subspace approximation we can then integrate the electronic degrees of freedom as

$$X(t + \delta t) = 2X(t) - X(t - \delta t) - \delta t^2 \omega^2 \sum_{i,j=1}^m V_i M_{i,j} \langle W_j, W_0 \rangle + \alpha \sum_{k=0}^{k_{\max}} c_k X(t - k\delta t). \quad (32)$$

Apart from the low-rank approximation of the inverse Jacobian kernel acting on the residual function in Eq. (31), with the matrices constructed as in Alg. 1, there are a number of alternative low-rank approximations that can be used. These techniques are discussed in the appendix of Ref. [35]. Those methods could also be adjusted to the density matrix formalism in analogy to the technique presented here. However, here I will only consider the rank- m approximation in Eq. (31) and Alg. 1.

Algorithm 1 This algorithm generates $\{V_i\}$, M , and $\{W_i\}$ for the kernel approximation, Eq. (31), in the integration of the electronic degrees of freedom, Eqs. (25) and (32), using a preconditioned rank- m Krylov subspace approximation of the inverse Jacobian kernel, where $(\mathcal{K}_0 \mathcal{J})^{-1} \mathcal{K}_0 (D[X]S - X) \approx \sum_{i,j}^m V_i M_{i,j} \langle W_j, W_0 \rangle$. The algorithm is based on the Krylov subspace approximation of the inverse Jacobian kernel presented in Ref. [35]. The inner product is given by $\langle V_i, V_j \rangle = \text{Tr}[V_i^T V_j]$, with the Frobenius matrix norm $\|V_i\| = \sqrt{\langle V_i, V_i \rangle}$. The trace conserving canonical density matrix perturbation, $\partial_\lambda D[F_0(X) + \lambda F_1(V_m)]|_{\lambda=0}$, can be performed with Alg. 2.

$$W_0 = \mathcal{K}_0(D[X] - X), \quad m = 0$$

while Error > Chosen Tolerance **do**

$$m = m + 1$$

$$V_m = W_{m-1}$$

$$V_m = V_m - \sum_{j=1}^{m-1} \langle V_i, V_j \rangle V_j$$

$$V_m = V_m \|V_m\|^{-1}$$

$$W_m = \mathcal{K}_0 \left(\partial_\lambda D[F_0(X) + \lambda F_1(V_m)]|_{\lambda=0} - V_m \right)$$

$$O_{ij} = \langle W_i, W_j \rangle, \quad i, j = 1, 2, \dots, m$$

$$M = O^{-1}$$

$$\text{Error} = \left\| \left(\sum_{i,j=1}^m W_i M_{i,j} \langle W_j, W_0 \rangle - W_0 \right) \right\| / \|W_0\|$$

end while

$$\Rightarrow (\mathcal{K}_0 \mathcal{J})^{-1} \mathcal{K}_0 (D[X]S - X) \approx \sum_{i,j}^m V_i M_{i,j} \langle W_j, W_0 \rangle$$

The calculation of W_m in Alg. 1 requires the directional derivatives of the density matrix,

$$\partial_\lambda D[F_0(X) + \lambda F_1(V_m)]|_{\lambda=0} = Z \left(\frac{\partial}{\partial \lambda} D^\perp [F_0^\perp + \lambda F_1^\perp(V_m)] \Big|_{\lambda=0} \right) Z^T, \quad (33)$$

where

$$F_0^\perp = Z^T F(X) Z \quad (34)$$

with

$$F(X) = h + G(XS^{-1}) \quad (35)$$

and

$$F_1^\perp(V_m) = Z^T G(V_m S^{-1}) Z. \quad (36)$$

The directional density matrix derivative,

$$D_1^\perp = \left. \frac{\partial}{\partial \lambda} D^\perp [F_0^\perp + \lambda F_1^\perp (V_m)] \right|_{\lambda=0}, \quad (37)$$

corresponds to a calculation of the first-order (traceless) response,

$$D_1^\perp = \left. \frac{\partial}{\partial \lambda} \left(e^{[\beta(F_0^\perp - \mu_0 I + \lambda(F_1^\perp - \mu_1 I))]} + I \right)^{-1} \right|_{\lambda=0}, \quad (38)$$

with respect to the perturbation $F_1^\perp$ in the Fockian. The chemical potential μ_0 in the density matrix derivative in Eq. (38) is assumed to be known and the first-order response in the chemical potential, μ_1 , is chosen such that

$$\text{Tr} [D_1^\perp] = 0. \quad (39)$$

This traceless density matrix response can be calculated using canonical density matrix perturbation theory [49]. An algorithm to calculate the density matrix response $D_1^\perp$, which is based on a simplified version of the canonical density matrix perturbation algorithm in Ref. [49], using a diagonal eigenbasis representation and assuming a known chemical potential μ_0 , is given in Alg. 2. It is constructed from a combination of a recursive Fermi-operator expansion scheme [41, 48] for fractional occupation numbers and density matrix perturbation theory [61]. Originally the chemical potential, μ_0 , and the chemical potential derivative, μ_1 , were assumed to be unknown and instead updated iteratively using a Newton-Raphson scheme based on linearizations of the density matrix and the density matrix response around approximate μ_0 and μ_1 . With an exact μ_0 known initially, the linearization of the density matrix response with respect to μ_1 is exact in a single step and no iterative adjustments are necessary. An alternative response calculation that is more similar to regular Rayleigh-Schrödinger perturbation theory for systems with fractional occupation numbers [62, 63], which also can be adjusted in the same way for the response in the chemical potential μ_1 as in Alg. 2, was recently proposed by Nishimoto [64].

Algorithm 2 Simplified version of the canonical density matrix perturbation algorithm in Ref. [49] in a diagonal matrix representation for first-order response calculations, assuming a known chemical potential μ_0 and a molecular orbital eigenbasis representation with eigenvectors, Q , of $F_0^\perp$. All matrices with superscript (0) are diagonal. Dominating $\mathcal{O}(N^3)$ cost is marked by two asterisks (*), where N is the matrix dimension. Input: μ_0 , Q , E , n , β or T_e , $F_0^\perp$, and $F_1^\perp$ ($F_0^\perp$ and $F_1^\perp$ in orthogonalized basis-set representation); Output: $D_1^\perp = \frac{\partial}{\partial \lambda} D^\perp[F_0^\perp + \lambda F_1^\perp]|_{\lambda=0}$; Optional

Output: $D_0 = QX^{(0)}Q^T$

μ_0 Chemical potential of the unperturbed system

Q Matrix of eigenvectors of the unperturbed system, i.e. where $Q^T F_0^\perp Q = E$

E Diagonal matrix of eigenvalues of the unperturbed system

n Number of recursion steps, typically $n \in [6, 10]$

$\beta = 1/(k_B T_e)$ Inverse temperature

$c = 2^{-2-n}\beta$ Initial normalization constant

$F^{(0)} = Q^T F_0^\perp Q = E$ Unperturbed Fockian in the diagonal eigenvalue representation

$F^{(1)} = Q^T F_1^\perp Q$ Perturbed Fockian in molecular orbital representation (*)

$X^{(0)} = \frac{1}{2}I - c(F^{(0)} - \mu_0 I)$ Initialization

$X^{(1)} = -cF^{(1)}$ Initialization

for $i = 1, n$ **do**

$X_{\text{tmp}}^{(1)} = X^{(0)}X^{(1)} + X^{(1)}X^{(0)}$ Diagonal $\times$ full matrix multiplications

$Y_{\text{tmp}}^{(0)} = \left(2X^{(0)}(X^{(0)} - I) + I\right)^{-1}$ Diagonal matrix inversion

$X^{(0)} = Y_{\text{tmp}}^{(0)}X^{(0)}X^{(0)}$ Diagonal $\times$ diagonal matrix multiplications

$X^{(1)} = Y_{\text{tmp}}^{(0)}(X_{\text{tmp}}^{(1)} + 2(X^{(1)} - X_{\text{tmp}}^{(1)})X^{(0)})$ Diagonal $\times$ full matrix multiplications

end for

$D_\mu^{(0)} = \beta X^{(0)}(I - X^{(0)})$ Diagonal density matrix derivative $dD^{(0)}/d\mu$

$\mu_1 = -\text{Tr}[X^{(1)}]/\text{Tr}[D_\mu^{(0)}]$ First-order response in from $\lambda F^{(1)}$

$D^{(1)} = X^{(1)} + D_\mu^{(0)}\mu_1$ Canonical (traceless) first-order density matrix response

$D_1^\perp = QD^{(1)}Q^T$ First-order response back to the original orthogonal basis-set representation (*)

Algorithm 1 and 2 represent a practical approach to integrate the electronic equations of motion in XL-BOMD as in Eq. (32) using a density matrix formalism for the extended electronic degrees of freedom. If the diagonalization of $F_0^\perp$ has been performed, no additional diagonalization is needed in the rank- m Krylov subspace approximation of the kernel. This means that the computational overhead of each extra rank in the low-rank approximation has a limited overhead compared to a full self-consistent field iteration, which also includes a diagonalization of the Fockian. A summary in terms of a computational prototype scheme for XL-BOMD using a density matrix formalism, expressed in a pseudo-code, is given below in Sec. IV.

IV. COMPUTATIONAL SCHEME FOR XL-BOMD USING A DENSITY MATRIX FORMALISM

To provide a practical guide for the implementations that is suitable for density-matrix based electronic structure codes, I will present a detailed computational scheme for the XL-BOMD framework using the thermal Hartree-Fock

theory within the density matrix formalism. The scheme can be generalized and applied also to other electronic structure methods where the electronic degrees of freedom is represented by the single-particle density matrix. The XL-BOMD scheme is presented with a pseudocode in Alg. 3 and represents a comprehensive summary of this article.

The algorithm starts after an initial full self-consistent field optimization of the ground state density matrix, $D_{\min}$, has been performed, which is attained at the constrained variational minimum in Eq. (1). Here $G(\mathbf{R}, P) = 2J(P) - K(P)$ are the Coulomb and exchange matrices in restricted Hartree-Fock theory calculated at the atomic configuration, $\mathbf{R}$. $\mathcal{U}(\mathbf{R}, X)$ is the shadow potential energy surface including the electronic entropy at an electronic temperature T_e , as given in Eq. (14). The electronic temperature is given by the inverse temperature $\beta = 1/(k_B T_e)$, where k_B is the Boltzmann constant. The XL-BOMD simulation starts after an initialization, where $X(t_0 - k\delta t) = D_{\min} S$, $k = 0, 1, 2, \dots, k_{\max}$ for some given configuration $\mathbf{R}_0$ and velocities $\dot{\mathbf{R}}_0$.

The integration follows the modified leapfrog Velocity Verlet scheme in Eq. (27). The force evaluations based on

$$\frac{\partial \mathcal{U}(\mathbf{R}, X)}{\partial R_I} = 2\text{Tr}[h_{R_I} D] + \text{Tr}[(2D - P)G_{R_I}] + \partial V_{nn}/\partial R_I - 2\text{Tr}[ZZ^T F D S_{R_I}], \quad (40)$$

include terms like

$$h_{R_I} = \frac{\partial h}{\partial R_I}, \quad (41)$$

$$S_{R_I} = \frac{\partial S}{\partial R_I}, \quad (42)$$

$$G_{R_I} = \left. \frac{\partial G(\mathbf{R}, P)}{\partial R_I} \right|_P, \quad (43)$$

and the Pulay force-term [65],

$$f_{\text{Pulay}} = -2\text{Tr}[ZZ^T F D S_{R_I}], \quad (44)$$

which has been adapted for fractional occupation numbers [39–41]. The inverse overlap factorization matrix, Z , is either chosen as the inverse square root of the overlap matrix, i.e. $Z = S^{-1/2}$, or some other matrix for which $Z^T S Z = I$ [66]. The quantum response calculation of $D_1^\perp$ can be performed with Alg. 2.

Algorithm 3 Pseudocode for a XL-BOMD simulation scheme in the spin-restricted Hartree-Fock approximation using a density matrix formalism, including fractional occupation numbers and the electronic entropy to account for finite electronic temperatures. The modified Leapfrog velocity Verlet integration scheme, Eq. (27), is used with the coefficients $\{c_k\}$, α and $\kappa = \delta t^2 \omega^2$ given in Ref. [34]. The degrees of freedom are the atomic positions $\mathbf{R}(t)$, their velocities $\dot{\mathbf{R}}(t)$, and the electronic degrees of freedom $X(t)$ corresponding to the product of the approximate density matrix and the overlap matrix, PS . The scheme assumes an initial ground state optimization of the density matrix, $D_{\min}$, to set the initial conditions. The matrix inner product $\langle X, Y \rangle = \text{Tr}[X^T Y]$ with the corresponding Frobenius matrix norm are used, where $\|X\| = \sqrt{\text{Tr}[X^T X]}$. A rank- m Krylov subspace approximation of the kernel $\mathcal{K}$ in the integration of the electronic degrees of freedom is used, Eqs. (30-32), based on Ref. [35].

δt , N_{steps} [Size and number of integration time steps]
 $\mathbf{R}(t_0) = \mathbf{R}_0$, $\dot{\mathbf{R}}(t_0) = \dot{\mathbf{R}}_0$ [Coordinates and velocities at $t = t_0$]
 $D = D_{\min}$ [Initial relaxed ground state density matrix for $\mathbf{R}_0$ at $t = t_0$]
 $S = S[\mathbf{R}(t_0)]$, $Z = S^{-1/2}$ [Initial overlap matrix and inverse overlap factor at $t = t_0$]
 $\mathcal{K}_0 = \mathcal{I}$ [No preconditioner used here]
 $X(t_0 - k\delta t) = DS$, $k = 0, 1, 2, \dots, k_{\max}$
 c_k , α , $\kappa = \delta t^2 \omega^2$ [Integration coefficients for the Verlet damping term, Ref. [34]]
 $\mathcal{U}(\mathbf{R}, X) = U(\mathbf{R}_0)$ [Initial potential energy at $t = t_0$]
 $\partial \mathcal{U}(\mathbf{R}, X) / \partial R_I = \partial U(\mathbf{R}_0) / \partial R_I$ [Initial force at $t = t_0$]
for $i = 1$, N_{steps} **do**
 $t = t_0 + (i - 1)\delta t$
 $E_{\text{tot}}(t) = (1/2) \sum_I M_I \dot{R}_I^2 + \mathcal{U}(\mathbf{R}, X)$ [Constant of motion]
 $\dot{R}_I(t + \delta t/2) = \dot{R}_I(t) - (\delta t/2) M_I^{-1} \partial \mathcal{U}(\mathbf{R}, X) / \partial R_I$ [first half of leapfrog step]
 $R_I(t + \delta t) = R_I(t) - \delta t \dot{R}_I(t + \delta t/2)$ [full leapfrog integration time step]
 $W_0 = \mathcal{K}_0(DS - X)$ [Residual]
 if $i = 1$ **then**
 $\ddot{X}(t) = W_0$
 else
 $m = 0$
 while (Error > Error Tolerance) **do**
 $m = m + 1$
 $V_m = W_{m-1}$
 for $j = 1$, $m-1$ **do**
 $V_m = V_m - \langle V_m, V_j \rangle V_j$ [Orthogonalization]
 end for
 $V_m = V_m / \|V_m\|$
 $\delta D = V_m S^{-1}$
 $F_1^\perp = Z^T G[\mathbf{R}(t + \delta t), \delta D] Z$
 $D_1^\perp = \partial D^\perp [F_0^\perp + \lambda F_1^\perp] / \partial \lambda |_{\lambda=0}$ [use Alg. 2]
 $W_m = \mathcal{K}_0(Z D_1^\perp Z^{-1} - V_m)$
 $O_{kl} = \langle W_k, W_l \rangle$, $k, l = 1, 2, \dots, m$
 $M = O^{-1}$
 $I_{\text{Res}} W_0 = \sum_{k,l=1}^m W_k M_{kl} \langle W_l, W_0 \rangle$
 Error = $\|I_{\text{Res}} W_0 - W_0\| / \|W_0\|$
 end while
 $\ddot{X}(t) = - \sum_{k,l=1}^m V_k M_{kl} \langle W_l, W_0 \rangle$ [as in Eqs. (31) and (30)]
 end if
 $X(t + \delta t) = 2X(t) - X(t - \delta t) + \kappa \ddot{X}(t) + \alpha \sum_{k=0}^{k_{\max}} c_k X(t - k\delta t)$ [as in Eq. (32)]
 $S = S[\mathbf{R}(t + \delta t)]$, $Z = S^{-1/2}$, $P = X(t + \delta t) S^{-1}$
 $V_{nn} = V_{nn}[\mathbf{R}(t + \delta t)]$ [update potential]
 $G = G[\mathbf{R}(t + \delta t), P]$, $F = h[\mathbf{R}(t + \delta t)] + G$, $F_0^\perp = Z^T F Z$
 Diagonalize $F_0^\perp$: $Q^T F_0^\perp Q = E$, where $E_{ij} = \delta_{ij} \epsilon_i$ and $Q^T Q = \delta_{ij}$, $f_i = \left(e^{\beta(\epsilon_i - \mu_0)} + 1 \right)^{-1}$
 $D^\perp = \left(e^{\beta(F_0^\perp - \mu_0 I)} + I \right)^{-1} = Q \left(e^{\beta(E - \mu_0 I)} + I \right)^{-1} Q^T$, $D = Z D^\perp Z^T$
 $\mathcal{U}(\mathbf{R}(t + \delta t), X) = 2\text{Tr}[hD] + \text{Tr}[(2D - P)G] - 2T_e \mathcal{S}(\{f_i\}) + V_{nn}$ [Shadow potential Eq. (14)]
 $\partial \mathcal{U}(\mathbf{R}, X) / \partial R_I = 2\text{Tr}[h_{R_I} D] + \text{Tr}[(2D - P)G_{R_I}] + \partial V_{nn} / \partial R_I - 2\text{Tr}[Z Z^T F D S_{R_I}]$
 $\dot{R}_I(t + \delta t) = \dot{R}_I(t + \delta t/2) - (\delta t/2) M_I^{-1} \partial \mathcal{U}(\mathbf{R}, X) / \partial R_I$ [second half of leapfrog step]
end for

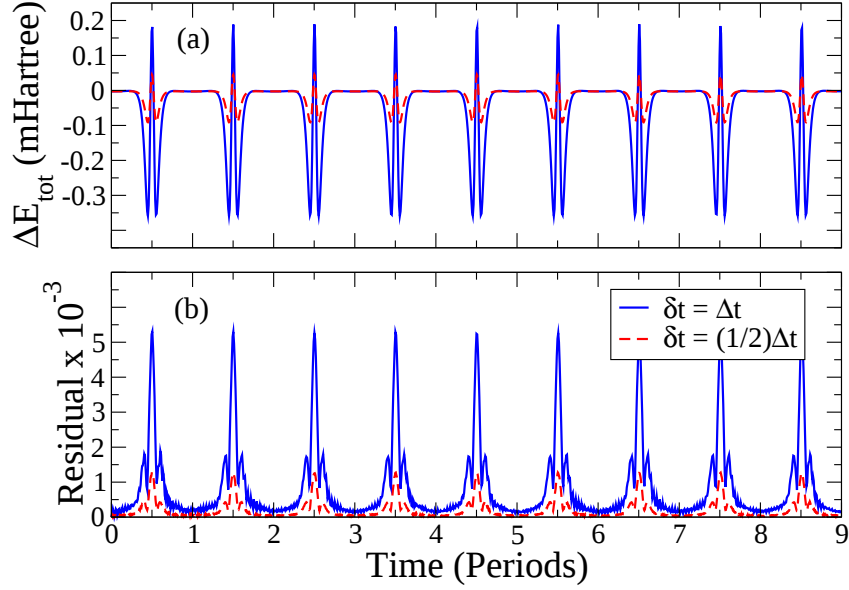


FIG. 1. The upper panel (a) shows the fluctuations in the total free energy, $\Delta E_{\text{tot}}(t) = E_{\text{tot}}(t) - E_{\text{tot}}(t_0)$, where $E_{\text{tot}} \equiv \mathcal{H}_{\text{XL-BOMD}}$ in Eq. (26), over 9 periods of oscillations for XL-BOMD simulations of a Hydrogen molecule at $T_e = 1,500$ K, using restricted, thermal Hartree-Fock theory in a density matrix formulation. The lower panel (b) shows the Frobenius norm of the residual function, $\|(D[X]S - X)\|$, as a function of the period of the oscillations. The size of the fluctuations approximately scales as $\sim \delta t^2$. The simulations were performed following the prototype scheme as outlined in the pseudocode in Alg. 3.

V. EXAMPLES

To illustrate XL-BOMD for a density matrix formulation using the thermal restricted Hartree-Fock theory, I will first use the example of a single hydrogen molecule with a basis set of 8 Gaussian atomic orbitals [67]. Thereafter, I will demonstrate a XL-BOMD simulations for a reactive mixture of nitromethane using semi-empirical self-consistent charge density functional tight-binding theory (SCC-DFTB) [23, 68–72] as implemented in a developers version of the open-source electronic structure software package LATTE [4, 73], with the parameterization given in Ref. [74]. The SCC-DFTB LATTE code was modified such that the density matrix was used as the extended electronic degrees of freedom instead of the net Mulliken charges. The implementations closely follow the general scheme in Alg. 3 both for the simulation based on Hartree-Fock and SCC-DFTB theory. For the coefficients of the modified Verlet integration scheme of the electronic degrees of freedom, $\{c_k\}$, α and $\kappa = \delta t^2 \omega^2$, I used the optimized values in Ref. [34] with $k_{\text{max}} = 6$ for the Hartree-Fock example and with $k_{\text{max}} = 5$ for the SCC-DFTB simulation. The number of recursion steps, n , used in the canonical density matrix perturbation scheme, Alg. 2, was set to $n = 8$.

A. A hydrogen molecule using thermal Hartree-Fock theory

The upper panel (a) of Fig. 2 shows the fluctuations in the total free energy, $\Delta E_{\text{tot}}(t) = E_{\text{tot}}(t) - E_{\text{tot}}(t_0)$, where $E_{\text{tot}} \equiv \mathcal{H}_{\text{XL-BOMD}}$ in Eq. (26), for XL-BOMD simulations of a Hydrogen molecule at $T_e = 1,500$ K. The fluctuations correspond to the local truncation error of the leapfrog velocity Verlet integration of the nuclear and electronic degrees of freedom in Eq. (27). The molecule is released without any initial velocity at an interatomic distance of 3 Bohr radius, which is over twice the equilibrium distance. The trajectories were followed back and forth over 9 periods of oscillations. The lower panel (b) shows the Frobenius norm of the residual function, $\|(D[X]S - X)\|$, as a function of time. The figure shows the result of two simulations using two different integration time steps, $\delta t = \Delta t$ and $\delta t = \Delta t/2$. As the integration time step is reduced by a factor of two, the size of the fluctuations in the total energy and in the residual function are reduced by a factor of about 4. This is what is expected from the Verlet-based integration scheme and the scaling of the amplitudes serves as a sensitive gauge on the accuracy of the implementation together with the absence of any visible systematic long-term drift in the total energy. The adaptive rank- m update was used together with a chosen relative error tolerance of 0.1 for the error term (Error) in Alg. 1. In all the simulations the rank, m , of the adaptive low-rank approximation was small, $m \leq 3$, with an average of 2.25 for $\delta t = \Delta t$ and 2.27 for $\delta t = \Delta t/2$. This indicates that the low-rank approximation of the kernel acting on the residual in the electronic degrees of freedom can be approximated accurately at low cost, without the need for preconditioning.

B. Reactive nitromethane using density functional tight-binding theory

Figure 2 shows the total energy fluctuations in the upper panel (a) of a reactive mixture of liquid nitromethane, with a few randomly swapped positions between N, C, O, and H atoms. Here $\Delta E_{\text{tot}}(t) = E_{\text{tot}}(t) - E_{\text{tot}}(t_0)$, where $E_{\text{tot}} \equiv \mathcal{H}_{\text{XL-BOMD}}$ in Eq. (26). This is a highly reactive molecular soup that most probably is unphysical, but it is a highly challenging simulation example and therefore well suited to evaluate the density-matrix based formulation of XL-BOMD. The statistical temperature (Temp.) quickly reaches over 2,000 K. At the same time the minute electronic HOMO-LUMO gap is rapidly opening and closing during the first half picosecond of simulation time. Several exothermic reactions occurs, seen as steps in the fluctuations of the statistical temperature in the middle panel (b). After some of these reactions, the amplitude of the total energy fluctuations increases fast, but is then followed by a slower reduction. This behavior indicates rapid local reactions, creating a few fast moving molecules, which then is followed by a thermal equilibration. The adaptive rank- m update was used together with a chosen relative error tolerance of 0.1 for the relative error term (Error) in Alg. 1. In the simulation m remained small, $m \leq 6$, with an average $\bar{m} = 3.64$. This demonstrates that the low-rank approximation of the kernel works well without preconditioning also for this more challenging example compared to the hydrogen molecule. The electronic temperature was set to $T_e = 2,000$ K. The fractional occupation numbers are of importance to avoid instabilities and too rapid changes in the electronic structure between time steps. The inclusion of an electronic temperature and entropy reduces transition barriers. A more precise *ab initio* description of bond breaking and bond formation may require multi-determinant wave functions and non-adiabatic effects, which is beyond the scope of this article.

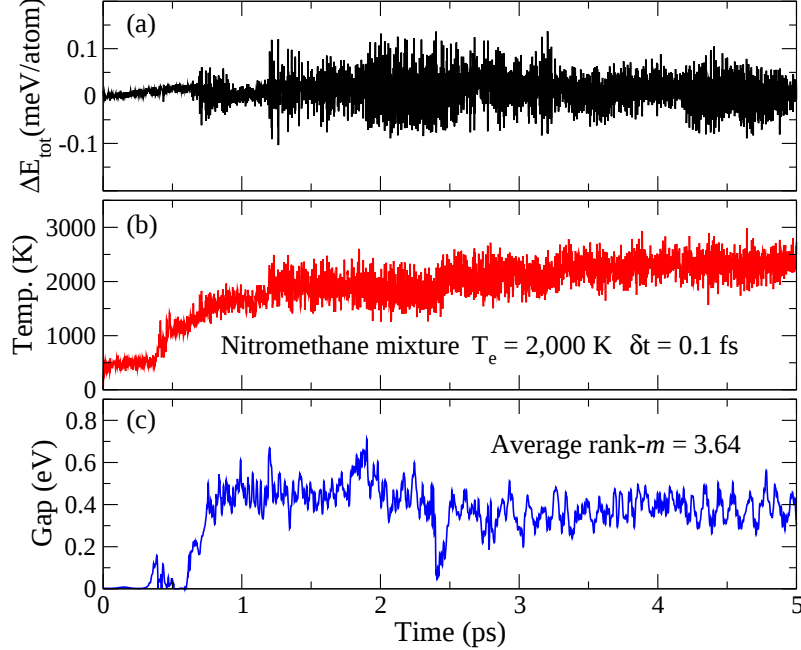


FIG. 2. The figure shows the results of a XL-BOMD simulation based on SCC-DFTB theory of a reactive mixture of liquid nitromethane, where the density matrix is used as the extended electronic degrees of freedom. The upper panel (a) shows the fluctuations in the total energy per atom and the middle panel (b) shows the statistical temperature (Temp.). The lower panel (c) shows the electronic gap, $\epsilon_{N_{\text{occ}}+1} - \epsilon_{N_{\text{occ}}}$, corresponding to the HOMO-LUMO gap at zero electronic temperature, $T_e = 0$ K. The simulation was performed following the prototype pseudocode as outlined in Alg. 3.

VI. SUMMARY AND DISCUSSION

I have presented XL-BOMD for Hartree-Fock theory using a density matrix formalism with fractional occupations numbers for the extended electronic degrees of freedom. In this case the metric tensor, $\mathcal{T} \equiv \mathcal{K}^T \mathcal{K}$, of the generalized extended harmonic oscillator is a 4th-order tensor. The corresponding kernel, $\mathcal{K}$, in the equations of motion for the extended electronic degrees of freedom then also represents a 4th-order tensor mapping between matrices. A tunable low-rank, Krylov subspace approximation of the kernel $\mathcal{K}$, which is defined as the inverse Jacobian of a residual matrix function, was presented for the integration of the extended electronic degrees of freedom. A computational scheme for the density-matrix based XL-BOMD simulations was given in pseudocode in Alg. 3, which summarizes the main results of this article. Examples for a single hydrogen molecule and a reactive mixture of liquid nitromethane were used to demonstrate the prototype code. No iterative self-consistent field optimization was required prior to the force evaluations (apart from the first time step), in contrast to regular direct Born-Oppenheimer molecular dynamics simulations. The tunable low-rank approximation worked well even without any preconditioner.

XL-BOMD may appear as a framework where we switch the problem of the non-linear self-consistent field optimization in direct Born-Oppenheimer molecular dynamics to a kernel approximation that requires the solution of

a system of non-linear equations in the integration of the extended electronic degrees of freedom. However, the kernel approximation is performed in a single step, requiring no additional diagonalization, whereas a non-linear self-consistent field optimization requires multiple steps involving a diagonalization in each iteration. Moreover, the forces and the molecular trajectories often show little sensitivity to the accuracy of the kernel approximation. In fact, for non-reactive chemical systems, it is often sufficient to approximate the kernel with a simple fixed scaled identity matrix. In contrast, the forces are not conservative in regular Born-Oppenheimer molecular dynamics, unless a tight self-consistent field convergence is reached, and the system often exhibit a systematic drift in the total energy where the system is artificially heated up or cooled down [16]. The problems are particularly difficult for reactive chemical system where it is often difficult and expensive to reach a sufficiently tight ground-state convergence in regular Born-Oppenheimer molecular dynamics simulations. Moreover, to use restarts from overlapping atomic densities in each new time step to avoid the systematic drift by restoring the time-reversal symmetry further increases the computational cost and may also introduce discontinuities if the solutions converge to different local minima between time steps. These shortcomings cannot be avoided by including thermostats [75]. In this way XL-BOMD combines computational speed with both stability and physical accuracy.

No preconditioner, K_0 , was proposed or used in the simulation examples. For the density-matrix based XL-BOMD, the preconditioner cannot be constructed explicitly and its form would depend on the specific electronic structure method that is used. Some possibilities for the design of preconditioners would include, for example, preconditioners based on the response of the individual diagonal atomic blocks of the density matrix at some given structure or some other selected coarse grained partial response, an approximate kernel for a related model problem like in Kerker mixing [76], or a fix low-rank preconditioner based on individual molecules or fragments for some approximate structure. The use of a preconditioner is ideal in XL-BOMD if it can be reused over many time steps. Chemical reactions are often rare events separated by thousands of time steps and an update of the preconditioner would then add little to the total cost of a simulation.

The formulation and algorithms in this article were presented mainly in the language of Hartree-Fock theory, which is suitable for quantum chemistry methods. However, the theory provides a general guide to implement XL-BOMD in a broad variety of electronic structure software packages using a density matrix formalism [26, 77–87]. The main purpose of this article is to facilitate such implementations.

XL-BOMD has many interesting similarities to extended Lagrangian Car-Parrinello molecular dynamics [5, 15–19] as is discussed in Ref. [13]. It also exhibit similar features to a new generation molecular dynamics schemes, where the electronic degrees of freedom is extrapolated or propagated dynamically [42, 88–93], as in Car-Parrinello molecular dynamics. In this way XL-BOMD can be viewed as a next generation extended Lagrangian first principles molecular dynamics.

The introduction of extended Lagrangian first principles molecular dynamics by Car and Parrinello in 1985 provided a first practical approach to general quantum-based molecular dynamics simulations at a theory level with predictive accuracy. Their innovation pioneered the rapid development of a number of advanced techniques, including highly efficient methods for direct Born-Oppenheimer molecular dynamics simulations [94–97] that currently dominate the

field. However, the extended Lagrangian approach to first principles molecular dynamics simulations may now, once again, appear to be the more efficient alternative.

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- [1] Niklasson, A. M. N. *Phys. Rev. Lett.* **2008**, *100*, 123004.
 - [2] Steneteg, P.; Abrikosov, I. A.; Weber, V.; Niklasson, A. M. N. *Phys. Rev. B* **2010**, *82*, 075110.
 - [3] Zheng, G.; Niklasson, A. M. N.; Karplus, M. *J. Chem. Phys.* **2011**, *135*, 044122.
 - [4] Cawkwell, M. J.; Niklasson, A. M. N. *J. Chem. Phys.* **2012**, *137*, 134105.
 - [5] Hutter, J. *WIREs Comput. Mol. Sci.* **2012**, *2*, 604.
 - [6] Lin, L.; Lu, J.; Shao, S. *Entropy* **2014**, *16*, 110.
 - [7] Arita, M.; Bowler, D. R.; Miyazaki, T. *J. Chem. Theory Comput.* **2014**, *10*, 5419.
 - [8] Souvatzis, P.; Niklasson, A. M. N. *J. Chem. Phys.* **2014**, *140*, 044117.
 - [9] Niklasson, A. M. N.; Cawkwell, M. *J. Chem. Phys.* **2014**, *141*, 164123.
 - [10] Nomura, K.; Small, P. E.; Kalia, R. K.; Nakano, A.; Vashista, P. *Comput. Phys. Comm.* **2015**, *192*, 91.
 - [11] Albaugh, A.; Demardash, O.; Head-Gordon, T. *J. Chem. Phys.* **2015**, *143*, 174104.
 - [12] Negre, C. F. A.; Mnizewski, S. M.; Cawkwell, M. J.; Bock, N.; Wall, M. E.; Niklasson, A. M. N. *J. Chem. Theory Comput.* **2016**, *12*, 3063.
 - [13] Niklasson, A. M. N. *J. Chem. Phys.* **2017**, *147*, 054103.
 - [14] Bjorgaard, J. A.; Sheppard, D.; Tretiak, S.; Niklasson, A. M. N. *Journal of Chemical Theory and Computation* **2018**, *14*, 799–806, PMID: 29316401.
 - [15] Car, R.; Parrinello, M. *Phys. Rev. Lett.* **1985**, *55*, 2471.
 - [16] Remler, D. K.; Madden, P. A. *Mol. Phys.* **1990**, *70*, 921.
 - [17] Pastore, G.; Smargassi, E.; Buda, F. *Phys. Rev. A* **1991**, *44*, 6334.
 - [18] Bornemann, F. A.; Schütte, C. *Numerische Mathematik* **1998**, *78*, 359.
 - [19] Marx, D.; Hutter, J. *Modern Methods and Algorithms of Quantum Chemistry*, 2nd ed.; ed. J. Grotendorst: John von Neumann Institute for Computing, Jülich, Germany, 2000.
 - [20] Niklasson, A. M. N.; Steneteg, P.; Bock, N. *J. Chem. Phys.* **2011**, *135*, 164111.
 - [21] Souvatzis, P.; Niklasson, A. M. N. *J. Chem. Phys.* **2013**, *139*, 214102.
 - [22] PetaChem, LLC, <http://www.petachem.com/doc/userguide.pdf> **2020**,
 - [23] Aradi, B.; Niklasson, A. M. N.; Frauenheim, T. *J. Chem. Theory Comput.* **2015**, *11*, 3357.
 - [24] Vitale, V.; Dziezic, J.; Albaugh, A.; Niklasson, A.; Head-Gordon, T. J.; Skylaris, C.-K. *J. Chem. Phys.* **2017**, *12*, 124115.

- [25] Lagardere, L.; Jolly, L.-H.; Lipparini, F.; Aviat, F.; Stamm, B.; Jing, Z. F.; Harger, M.; Torabifard, H.; Cisneros, G. A.; Schnieders, M. J.; Gresh, N.; Maday, Y.; Ren, P. Y.; Ponder, J. W.; Piquemal, J.-P. *Chem. Sci.* **2018**, –.
- [26] Peters, L. D. M.; Kussmann, J.; Ochsenfeld, C. *J. Chem. Theory Comput.* **2015**, *13*, 5479.
- [27] Otsuka, T.; Taiji, M.; Bowler, D. R.; Miyazaki, T. *Japanese Journal of Applied Physics* **2016**, *55*, 1102B1.
- [28] Hirakawa, T.; Suzuki, T.; Bowler, D. R.; Miyazaki, T. *J. Phys.: Condens. Matter* **2017**, *29*, 405901.
- [29] Albaugh, A.; Niklasson, A.; Head-Gordon, T. *J. Phys. Chem. Lett.* **2017**, *8*, 1714.
- [30] Albaugh, A.; Head-Gordon, T. *J. Chem. Theory Comput.* **2017**, *13*, 5207.
- [31] Albaugh, A.; Head-Gordon, T.; Niklasson, A. M. N. *Journal of Chemical Theory and Computation* **2018**, *14*, 499–511, PMID: 29316388.
- [32] Henning, P.; Niklasson, A. M. N. *ArXiv* <https://arxiv.org/abs/1912.10303> **2019**,
- [33] Niklasson, A. M. N.; Tymczak, C. J.; Challacombe, M. *Phys. Rev. Lett.* **2006**, *97*, 123001.
- [34] Niklasson, A. M. N.; Steneteg, P.; Odell, A.; Bock, N.; Challacombe, M.; Tymczak, C. J.; Holmstrom, E.; Zheng, G.; Weber, V. *J. Chem. Phys.* **2009**, *130*, 214109.
- [35] Niklasson, A. M. N. *J. Chem. Phys.* **2020**, *152*, 104103.
- [36] Roothaan, C. C. J. *Rev. Mod. Phys.* **1951**, *23*, 69–89.
- [37] McWeeny, R. *Rev. Mod. Phys.* **1960**, *32*, 335.
- [38] Mermin, N. D. *Annals of Physics* **1963**, *21*, 99.
- [39] Weinert, M.; Davenport, J. W. *Phys. Rev. B* **1992**, *45*, R13709.
- [40] Wentzcovitch, R. M.; Martins, J. L.; Allen, P. B. *Phys. Rev. B* **1992**, *45*, R11372.
- [41] Niklasson, A. M. N. *J. Chem. Phys.* **2008**, *129*, 244107.
- [42] Pulay, P.; Fogarasi, G. *Chem. Phys. Lett.* **2004**, *386*, 272.
- [43] Niklasson, A. M. N.; Tymczak, C. J.; Challacombe, M. *J. Chem. Phys.* **2007**, *126*, 144103.
- [44] Goedecker, S.; Colombo, L. *Phys. Rev. Lett.* **1994**, *73*, 122–125.
- [45] Silver, R. N.; Roder, H. *Int. J. Mod. Phys. C* **1994**, *5*, 735.
- [46] Silver, R. N.; Roder, H.; Voter, A. F.; Kress, J. D. *Int. J. Comput. Phys.* **1996**, *124*, 115.
- [47] Weisse, A.; Wellein, G.; Alvermann, A.; Fehske, H. *Rev. Mod. Phys.* **2006**, *78*, 275.
- [48] Niklasson, A. M. N. *Phys. Rev. B* **2003**, *68*, 233104.
- [49] Niklasson, A. M. N.; Cawksell, M. J.; Rubensson, E. H.; Rudberg, E. *Phys. Rev. E* **2015**, *92*, 063301.
- [50] Goedecker, S. *Rev. Mod. Phys.* **1999**, *71*, 1085–1123.
- [51] Bowler, D. R.; Miyazaki, T. *Rep. Prog. Phys.* **2012**, *75*, 036503–036546.
- [52] Heitler, W.; London, F. *Z. Phys.* **1927**, *44*, 455.
- [53] Born, M.; Oppenheimer, R. *Ann. Phys.* **1927**, *389*, 475.
- [54] Odell, A.; Delin, A.; Johansson, B.; Bock, N.; Challacombe, M.; Niklasson, A. M. N. *J. Chem. Phys.* **2009**, *131*, 244106.
- [55] Odell, A.; Delin, A.; Johansson, B.; Cawksell, M. J.; Niklasson, A. M. N. *J. Chem. Phys.* **2011**, *135*, 224105.
- [56] Knoll, D.; Keyes, D. *J. Comput. Phys.* **2004**, *193*, 357.
- [57] Anderson, D. G. *J. Assoc. Comput. Mach.* **1965**, *12*, 547.
- [58] Saad, Y.; Schultz, M. H. *SIAM J. Sci. Stat. Comput.* **1986**, *7*, 856.
- [59] Saad, Y. *Iterative methods for Sparse Linear Systems*; PWS Publishing: Boston, 1996.
- [60] Niklasson, A. M. N. unpublished.
- [61] Niklasson, A. M. N.; Challacombe, M. *Phys. Rev. Lett.* **2004**, *92*, 193001.

- [62] Adler, S. L. *Phys. Rev.* **1962**, *126*, 413.
- [63] Wiser, N. *Phys. Rev.* **1963**, *129*, 62.
- [64] Nishimoto, Y. *J. Chem. Phys.* **2017**, *146*, 084101.
- [65] Pulay, P. *Mol. Phys.* **1969**, *17*, 197–204.
- [66] Niklasson, A. M. N. *Phys. Rev. B* **2004**, *70*, 193102.
- [67] Thijssen, J. M. *Computational Physics*; Cambridge University Press, 1999.
- [68] Elstner, M.; Poresag, D.; Jungnickel, G.; Elsner, J.; Haugk, M.; Frauenheim, T.; Suhai, S.; Seifert, G. *Phys. Rev. B* **1998**, *58*, 7260.
- [69] Finnis, M. W.; Paxton, A. T.; Methfessel, M.; van Schilfgarde, M. *Phys. Rev. Lett.* **1998**, *81*, 5149.
- [70] Frauenheim, T.; Seifert, G.; and Z. Hajnal, M. E.; Jungnickel, G.; Poresag, D.; Suhai, S.; Scholz, R. *Phys. Stat. sol.* **2000**, *217*, 41.
- [71] Gaus, M.; Cui, Q.; Elstner, M. *J. Chem. Theory Comput.* **2011**, *7*, 931.
- [72] et al., B. H. *J. Chem. Phys.* **2020**, *152*, 0000.
- [73] Cawwell, M. J.; et al., LATTE. 2010; Los Alamos National Laboratory (LA-CC-10004), <http://www.github.com/lanl/latte>.
- [74] Krishnapryian, A.; Yang, P.; Niklasson, A. M. N.; Cawwell, M. J. *J. Chem. Theory Comput.* **2017**, *13*, 6191.
- [75] Martinez, E.; Cawwell, M. J.; Voter, A. F.; Niklasson, A. M. N. *J. Chem. Phys.* **2015**, *142*, 1770.
- [76] Kerker, G. P. *Phys. Rev. B* **1981**, *23*, 3082–3084.
- [77] Schmidt, M. W.; Baldridge, K. K.; Boatz, J. A.; Elbert, S. T.; Gordon, M. S.; Jensen, J. H.; Koseki, S.; Matsunaga, N.; Nguyen, K. A.; Su, S.; Windus, T. L.; Dupuis, M.; Montgomery, J. A. *J. Comp. Chem.* **1993**, *14*, 1347.
- [78] Frisch, M. J. et al. Gaussian 94, Revision B.3. GAUSSIAN, 1994.
- [79] Stewart, J. P. *Int. J. Quant. Chem.* **1996**, *58*, 133.
- [80] Soler, J. M.; Artacho, E.; Gale, J. D.; Garcia, A.; Junquera, J.; Ordejon, P.; Sanchez-Portal, D. *J. Phys.: Condens. Matter* **2002**, *14*, 2745.
- [81] Bowler, D. R.; Choudhury, R.; Gillan, M. J.; Miyazaki, T. *Phys. Stat. Sol. B* **2006**, *243*, 898–1000.
- [82] Hine, N. D.; Haynes, P. D.; Mostofi, A. A.; Skylaris, C.-K.; Payne, M. C. *Comput. Phys. Comm.* **2009**, *180*, 1041–1053.
- [83] Kendall, R. A.; Apra, E.; Bernholdt, D. E.; Bylaska, E. J.; Dupuis, M.; Fann, G. I.; Harrison, R. J.; Ju, J.; Nichols, J. A.; Nieplocha, J.; Straatsma, T. P.; Windus, T. L.; Wong, A. T. *Comput. Phys. Commun.* **2000**, *128*, 260.
- [84] VandeVondele, J.; Krack, M.; Mohammed, F.; Parrinello, M.; Chassing, T.; Hutter, J. *Comput. Phys. Commun.* **2005**, *167*, 103.
- [85] Aradi, B.; Hourahine, B.; Frauenheim, T. *The Journal of Physical Chemistry A* **2007**, *111*, 5678–5684.
- [86] Rudberg, E.; Rubensson, E. H.; Salek, P. *J. Chem. Theory Comput.* **2011**, *7*, 340.
- [87] Levchenko, S. V.; Ren, X.; Wieferink, J.; Johanni, R.; Rinke, P.; Blum, V.; Scheffler, M. *Comput. Phys. Comm.* **2015**, *192*, 60.
- [88] Herbert, J.; Head-Gordon, M. *Phys. Chem. Chem. Phys.* **2005**, *7*, 3269.
- [89] Kühne, T. D.; Krack, M.; Mohamed, F. R.; Parrinello, M. *Phys. Rev. Lett.* **2007**, *98*, 066401.
- [90] Atsumi, T.; Nakai, H. *Comput. Phys. Commun.* **2008**, *167*, 103.
- [91] Fang, J.; Gao, X.; Song, H.; Wang, H. *J. Chem. Phys* **2016**, *144*, 244103.
- [92] Coretti, A.; Bonella, S.; Ciccotti, G. *J. Chem. Phys.* **2018**, *149*, 191102.
- [93] Bonella, S.; Coretti, A.; Vuilleumier, R.; Ciccotti, G. <https://arxiv.org/pdf/2001.03556.pdf> **2020**,

- [94] Payne, M. C.; Teter, M. P.; Allan, D. C.; Arias, T. A.; Joannopoulos, J. D. *Rev. Mod. Phys.* **1992**, *64*, 1045.
- [95] Arias, T.; Payne, M.; Joannopoulos, J. *Phys. Rev. B* **1992**, *45*, 1538.
- [96] Barnett, R. N.; Landman, U. *Phys. Rev. B* **1993**, *48*, 2081.
- [97] Kresse, G.; Hafner, J. *Phys. Rev. B* **1993**, *47*, 558.